

MDL-III-785L/1~100mW



INFRARED DIODE LASER AT 785nm

It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Central wavelength (nm)	785 ±5
Operating mode	CW
Output power (mW)	> 10, 20, ..., 100
Power stability (rms, over 4 hours)	<1%, <2%, <3% (<0.5%, optional)
Transverse mode	Near TEM ₀₀
M ² factor	<1.5
Beam diameter at the aperture (1/e ² ,mm)	~4
Beam divergence, full angle (mrad)	<1
Polarization ratio	>50:1 (>100:1, optional) Horizontal ±5 degree (Vertical Optional)
Warm-up time (minutes)	<5
Pointing stability after warm-up (mrad)	<0.05
Beam height from base plate (mm)	24.8
Operating temperature (°C)	10~35
Power supply	85-264VAC PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz) 100-240VAC PSU-A-D (Frequency for 30kHz -100kHz)
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional
Expected lifetime (hours)	10000
Warranty	1 year



MDL-III-785L	PSU-III-LED	PSU-III-FDA	PSU-A-D
143.5(L)×73(W) ×46.2(H) mm³, 0.7kg	188.6 (L) ×155(W) ×92 (H) mm³, 1.5kg	171(L) ×130(W) ×62.2 (H) mm³, 1.2kg	162(L) ×144(W) ×70 (H) mm³, 1.0kg